

## CMOS 4-BIT MICROCONTROLLER

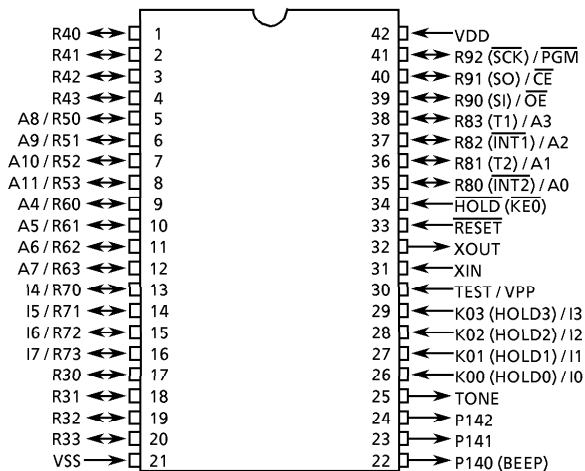
**TMP47P407VN**  
**TMP47P407VF**

The 47P407V is the OTP microcontroller with 32kbits PROM. For program operation, the programming is achieved by using with EPROM programmer (TMM2764AD type) and adapter socket (BM1120, BM1121). A.C./D.C characteristics are equivalent to Mask-programed ROM device.

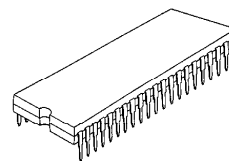
PART No.	ROM	RAM	PACKAGE	ADAPTER SOCKET
TMP47P407VN	OTP		SDIP42-P-600-1.78	BM1120
TMP47P407VF	4096 × 8-bit	768 × 4-bit	QFP44-P-1414-0.80D	BM1121

## PIN ASSIGNMENT (TOP VIEW)

SDIP42-P-600-1.78



SDIP42-P-600-1.78



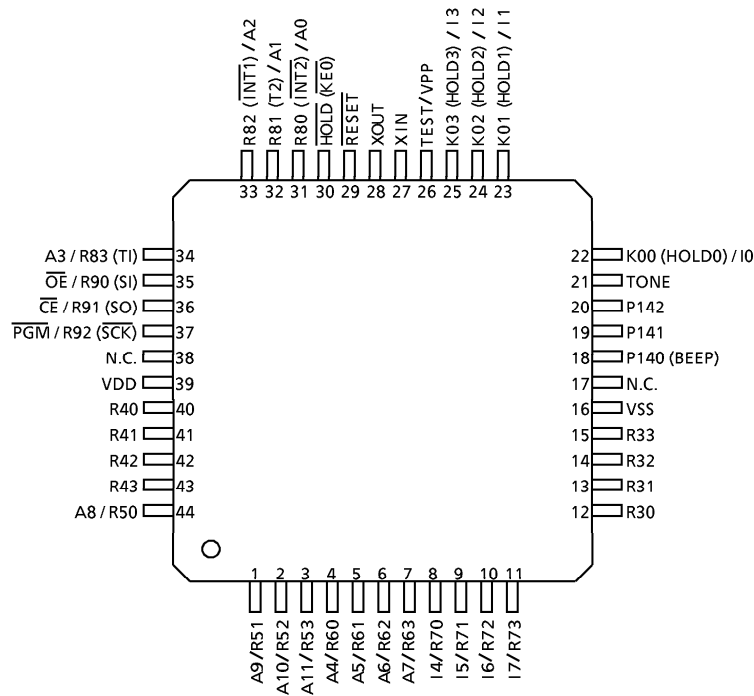
TMP47P407VN

980901EBP1

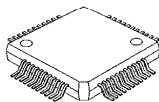
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PIN ASSIGNMENT (TOP VIEW)

QFP44-P-1414-0.80D



QFP44-P-1414-0.80D



TMP47P407VF

## PIN FUNCTION

The 47P407V has MCU mode and PROM mode.

## (1) MCU mode

The 47C407A and the 47P407V are pin compatible (TEST pin for out-going test. Be fixed to low level).

## (2) PROM mode

PIN NAME	Input/Output	FUNCTIONS	PIN NAME (MCU MODE)
A11 to A8	Input	Address inputs	R53 to R50
A7 to A4			R63 to R60
A3 to A0			R83 to R80
I7 to I4	I/O	Data inputs / outputs	R73 to R70
I3 to I0			K03 to K00
$\overline{\text{PGM}}$	Input	Program control input	R92
$\overline{\text{CE}}$		Chip Enable input	R91
$\overline{\text{OE}}$		Output Enable input	R90
VPP	Power supply	+ 12.5V / 5V (Program supply voltage)	TEST
VCC		+ 5V	VDD
VSS		0V	VSS
TONE	Output	Open	
R33 to R30	I/O	Be fixed to low level	
R43 to R40			
P142 to P140	Output	Open	
$\overline{\text{RESET}}$	Input	PROM mode setting pins. Be fixed to low level.	
$\overline{\text{HOLD}}$	Input		
XIN	Input	External clock input (to keep the internal state stable)	
XOUT	Output	Open	

## OPERATIONAL DESCRIPTION

The following is an explanation of hardware configuration and operation in relation to the 47P407V. The 47P407V is the same as the 47C407A except that an OTP is used instead of a Mask ROM.

### 1. OPERATION MODE

The 47P407V has an MCU mode and a PROM mode.

#### 1.1 MCU Mode

The MCU mode is set by fixing the TEST / VPP pin at the "L" level. Operation in the MCU mode is the same as for the 47C407A, except that the TEST / VPP pin does not have pull-down resistor and cannot be used open.

##### 1.1.1 Program Memory

The program storage area is the same as for the 47C407A.

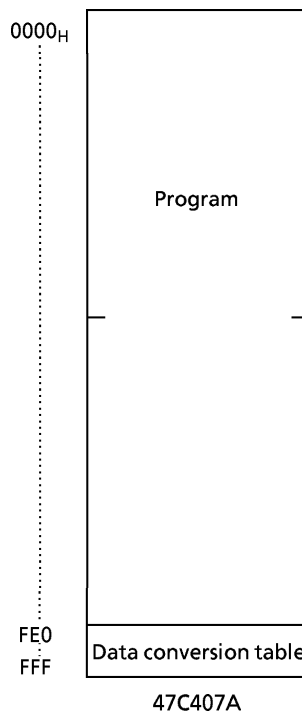


Figure 1-1. Program area

##### 1.1.2 Data Memory

The 47P407V has 768 × 4-bit data memory.

##### 1.1.3 Input/Output Circuitry

(1) Control pins

This is the same as for the 47C407A except that there is no built-in pull-down resistance for the TEST pin.

(2) I/O Ports

The input/output circuit of the 47P407V is the same as I/O code WB of the 47C407A.

External resistance, for example, is required when using as evaluator of other I/O codes (WE, WH) (Refer to Figure 1-2).

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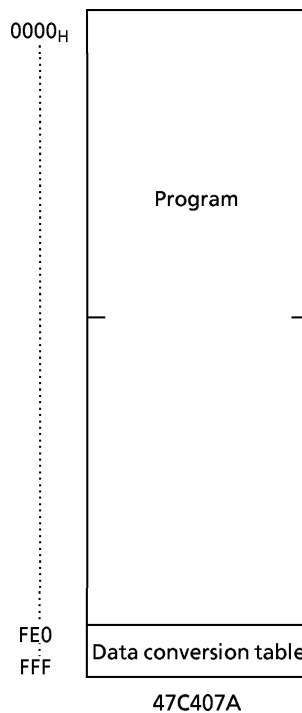


Figure 1-1. Program area

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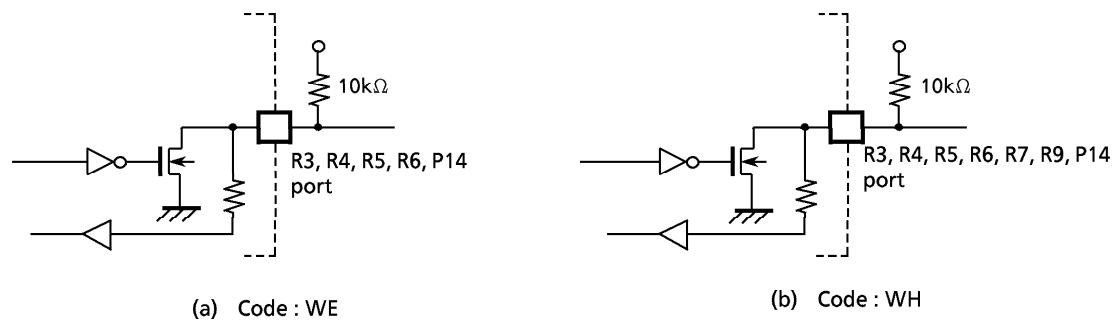


Figure 1-2. I/O code and external circuitry

## 1.2 PROM Mode

The PROM mode is set by setting the  $\overline{\text{RESET}}$ ,  $\overline{\text{HOLD}}$  pins to the "L" level. The PROM mode can be used as a general-purpose PROM writer for program writing and verification (A high-speed program mode is used set the ROM type the same as for the TMM2764AD).

An adapter socket (part No. BM1120 / BM1121) is available for connecting a PROM writer.

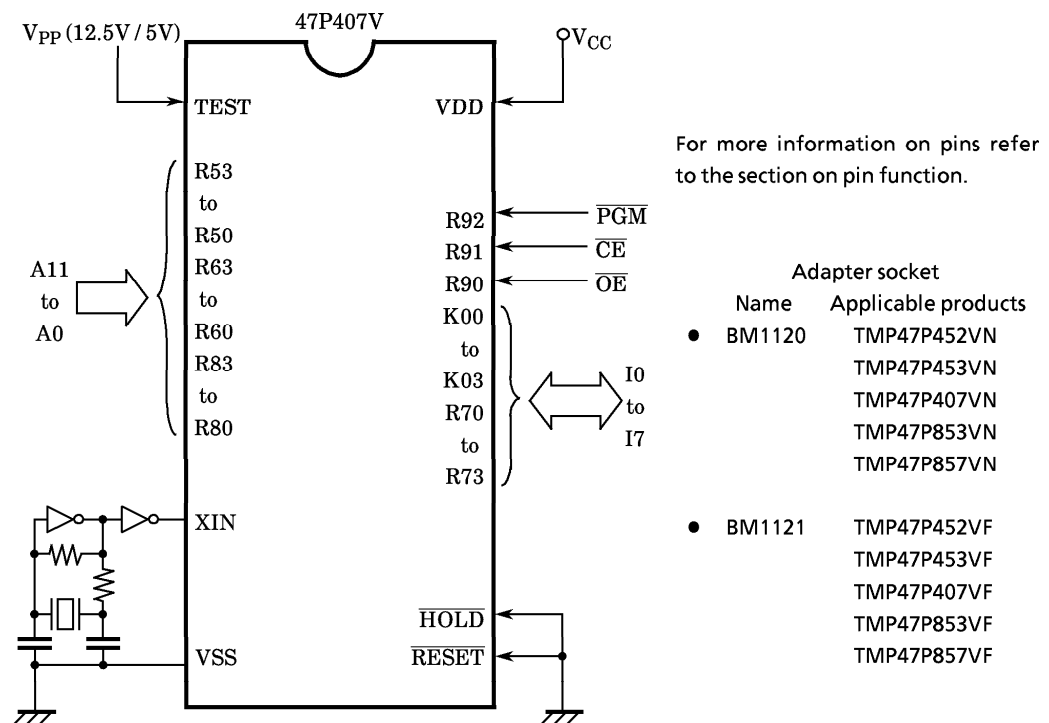


Figure 1-3. Setting for PROM mode

### 1.2.1 Writing

Set the PROM writer ROM to TMM2764AD (64k-bit), or equivalent. Before writing to a 47P407V (32k-bit), set the data area for writing to 32k-bits (start address: 0000<sub>H</sub>, ending address: 0FFF<sub>H</sub>), or else load the same data to the first 32k bits (0000<sub>H</sub>-0FFF<sub>H</sub>) and the second 32k bits (1000<sub>H</sub>-1FFF<sub>H</sub>).

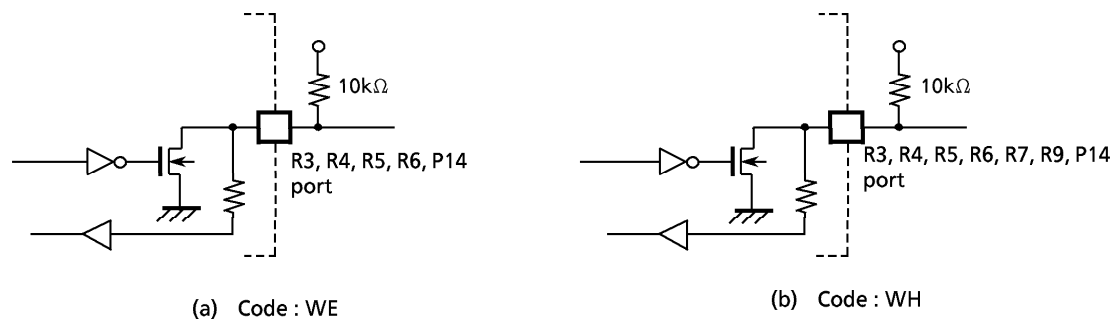


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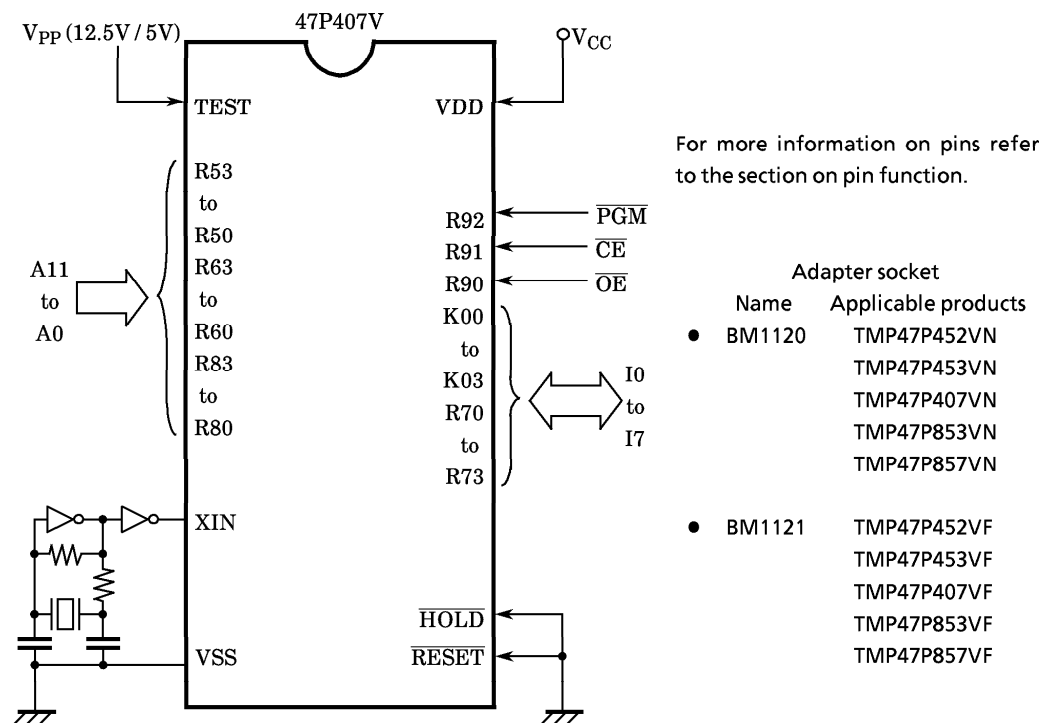


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### 1.2.2 High Speed Programming Mode

The device is set up in the high speed programming mode when the programming voltage (12.5V) is applied to the Vpp terminal with Vcc = 6V and PGM = VIH4. The programming is achieved by applying a Single TTL low level 1 ms, pulse the PGM input after addresses and data are stable. Then the programmed data is verified by using program Verify Mode. If the programmed data is not correct, another program pulse of 1 ms is applied and then programmed data is verified. This should be repeated until the program operates correctly (max. 15 times). After correctly programming the selected address, one additional program pulse with pulse width 4 times that needed for programming is applied. When programming has been completed, the data in all addresses should be verified with Vcc = Vpp = 5V.

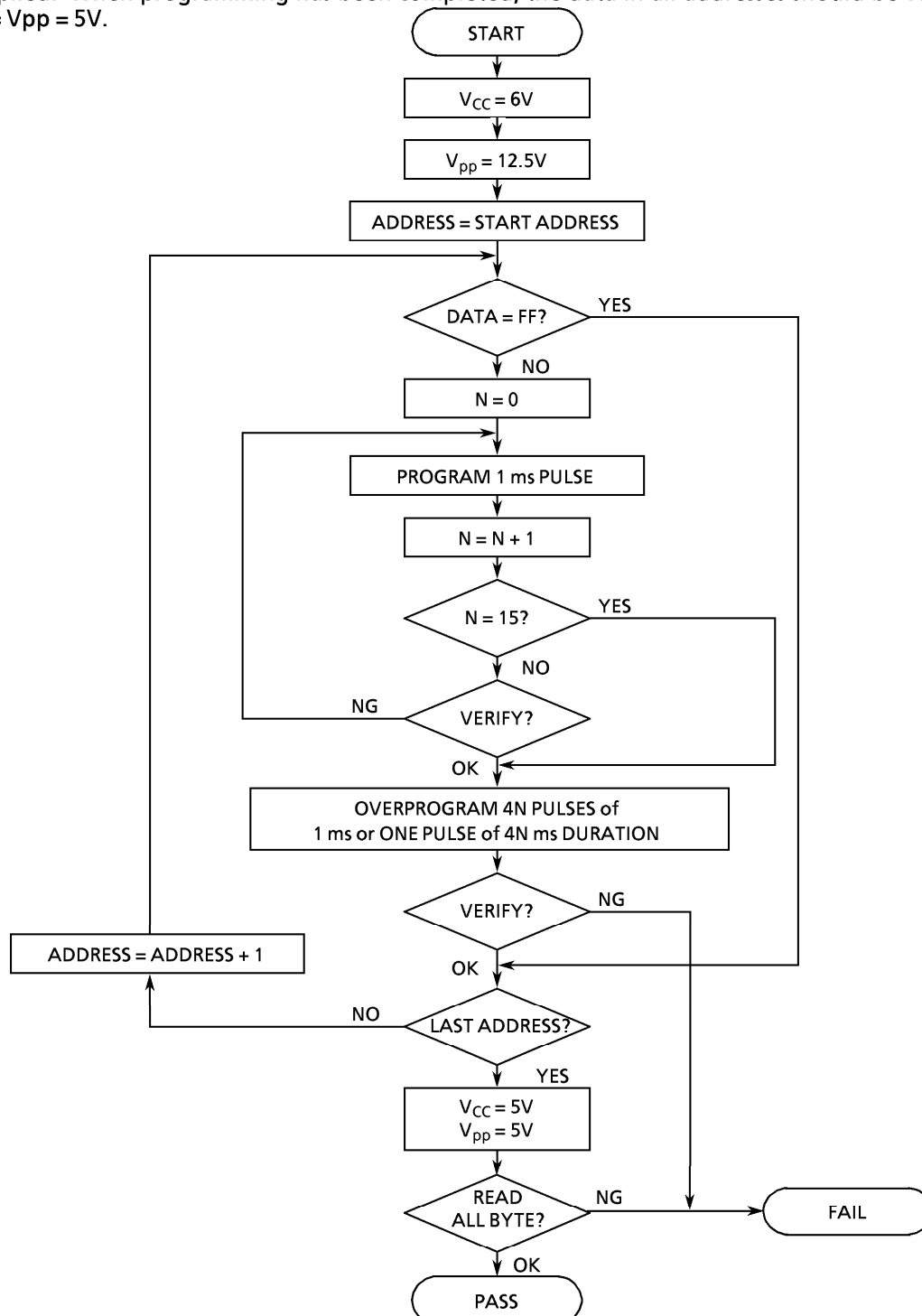


Figure1-4. FLOW CHART



## ELECTRICAL CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS (V<sub>SS</sub> = 0V)

PARAMETER	SYMBOL	PINS	RATINGS	UNIT
Supply Voltage	V <sub>DD</sub>		– 0.3 to 7	V
Program Voltage	V <sub>PP</sub>	TEST/VPP pin	– 0.3 to 14.0	V
Input Voltage	V <sub>IN</sub>		– 0.3 to V <sub>DD</sub> + 0.3	V
Output Voltage	V <sub>OUT1</sub>	Except sink open drain pin, but include R7	– 0.3 to V <sub>DD</sub> + 0.3	V
	V <sub>OUT2</sub>	Sink open drain pin except R7	– 0.3 to 10	
Output Current (per 1 pin)	I <sub>OUT</sub>		3.2	mA
Power Dissipation (T <sub>opr</sub> = 60°C)	PD		600	mW
Soldering Temperature (time)	T <sub>sld</sub>		260 (10s)	°C
Storage Temperature	T <sub>stg</sub>		– 55 to 125	°C
Operating Temperature	T <sub>opr</sub>		– 30 to 60	°C

Note. Characteristic of R7 is different from 47C407A

RECOMMENDED OPERATING CONDITIONS (V<sub>SS</sub> = 0V, T<sub>opr</sub> = – 30 to 60°C)

PARAMETER	SYMBOL	PINS	CONDITIONS	Min.	Max.	UNIT
Supply Voltage	V <sub>DD</sub>		In the Normal mode	2.7	6.0	V
			In the HOLD mode	2.0		
Input High Voltage	V <sub>IH1</sub>	Except hysteresis input	V <sub>DD</sub> ≥ 4.5V	V <sub>DD</sub> × 0.7	V <sub>DD</sub>	V
	V <sub>IH2</sub>	Hysteresis input		V <sub>DD</sub> × 0.75		
	V <sub>IH3</sub>		V <sub>DD</sub> < 4.5V	V <sub>DD</sub> × 0.9		
Input Low Voltage	V <sub>IL1</sub>	Except hysteresis input	V <sub>DD</sub> ≥ 4.5V	0	V <sub>DD</sub> × 0.3	V
	V <sub>IL2</sub>	Hysteresis input			V <sub>DD</sub> × 0.25	
	V <sub>IL3</sub>		V <sub>DD</sub> < 4.5V		V <sub>DD</sub> × 0.1	
Clock Frequency	f <sub>c</sub>			3.84		MHz

D.C. CHARACTERISTICS	( $V_{SS} = 0V$ , $V_{DD} = 2.7$ to $6.0V$ , $T_{opr} = -30$ to $60^{\circ}C$ )
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PARAMETER	SYMBOL	PINS	CONDITIONS	Min.	Typ.	Max.	UNIT
Hysteresis Voltage	$V_{HS}$	Hysteresis Input		—	0.7	—	V
Input Current	$I_{IN1}$	Port, K0 TEST, $\overline{RESET}$ , $\overline{HOLD}$	$V_{DD} = 5.5V$ ,	—	—	$\pm 2$	$\mu A$
	$I_{IN2}$	Port R (open drain)	$V_{IN} = 5.5V / 0V$				
Input Low Current	$I_{IL}$	Port R (push-pull)	$V_{DD} = 5.5V$ , $V_{IN} = 0.4V$	—	—	— 2	mA
Input Resistance	$R_{IN1}$	Port K0		30	70	150	k $\Omega$
	$R_{IN2}$	$\overline{RESET}$		100	220	450	
Output Leakage Current	$I_{LO}$	Ports P, R (open drain)	$V_{DD} = 5.5V$ , $V_{OUT} = 5.5V$	—	—	2	$\mu A$
Output High Voltage	$V_{OH}$	Port R (push-pull)	$V_{DD} = 4.5V$ , $I_{OH} = -200\mu A$	2.4	—	—	V
Output Low Voltage	$V_{OL2}$	Except XOUT	$V_{DD} = 4.5V$ , $I_{OL} = 1.6mA$	—	—	0.4	V
Supply Current (in the Normal mode)	$I_{DD}$		Except TONE generating $V_{DD} = 5.5V$ , $f_c = 3.84MHz$	—	3	6	mA
	$I_{DDT}$		TONE generating $V_{DD} = 5.5V$ , $f_c = 3.84MHz$	—	5	10	
Supply Current (in the HOLD mode)	$I_{DDH}$		$V_{DD} = 5.5V$	—	0.5	10	$\mu A$

Note 1. Typ values show those at  $T_{opr} = 25^{\circ}C$ ,  $V_{DD} = 5V$

Note 2. Input Current  $I_{IN1}$  ; The current through resistor is not included, when the pull-up / pull-down resistor is contained.

Note 3. Supply Current ;  $V_{IN} = 5.3/0.2V$   
 The K0 port is opened when the pull-up/pull-down resistor is contained.  
 The voltage applied to the R port is within the valid range  $V_{IL}$  or  $V_{IH}$ .

TONE OUTPUT CHARACTERISTICS
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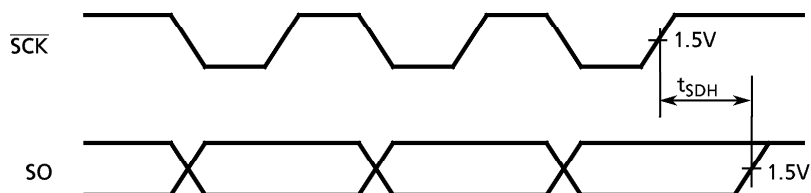
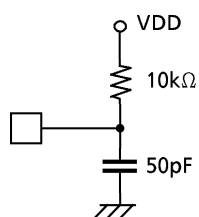
( $V_{SS} = 0V$ ,  $V_{DD} = 2.7$  to  $6.0V$ ,  $T_{opr} = -30$  to  $60^{\circ}C$ )

PARAMETER	SYMBOL	CONDITIONS	Min.	Typ.	Max.	UNIT
Tone Output Voltage (ROW)	$V_{TONE}$	$R_L \geq 10k\Omega$ , $V_{DD} = 3.0V$	135	200	260	mVrms
Tone Output Pre-Emphasis High Band	PEHB	PEHB = $20\log (COL/ROW)$	1	2	3	dB
Tone Output Distortion	DIS		—	—	10	%
Tone Output Frequency Stability	$\Delta f$	Except error of osc. frequency	—	—	0.7	%

## A.C. CHARACTERISTICS

(V<sub>SS</sub> = 0V, V<sub>DD</sub> = 2.7 to 6.0V, T<sub>opr</sub> = -30 to 60°C)

PARAMETER	SYMBOL	CONDITIONS	Min.	Typ.	Max.	UNIT
Instruction Cycle Time	t <sub>cy</sub>		2.1			μs
High level Clock pulse Width	t <sub>WCH</sub>	External clock mode	80	—	—	ns
Low level Clock pulse Width	t <sub>WCL</sub>					
Shift Data Hold Time	t <sub>SDH</sub>		0.5t <sub>cy</sub> -300	—	—	ns

**Note. Shift Data Hold Time :***External circuit for  $\overline{SCK}$  pin and SO pin      Serial port (completion of transmisson)*

## RECOMMENDED OSCILLATING CONDITIONS

(V<sub>SS</sub> = 0V, V<sub>DD</sub> = 2.7 to 6.0V, T<sub>opr</sub> = -30 to 60°C)

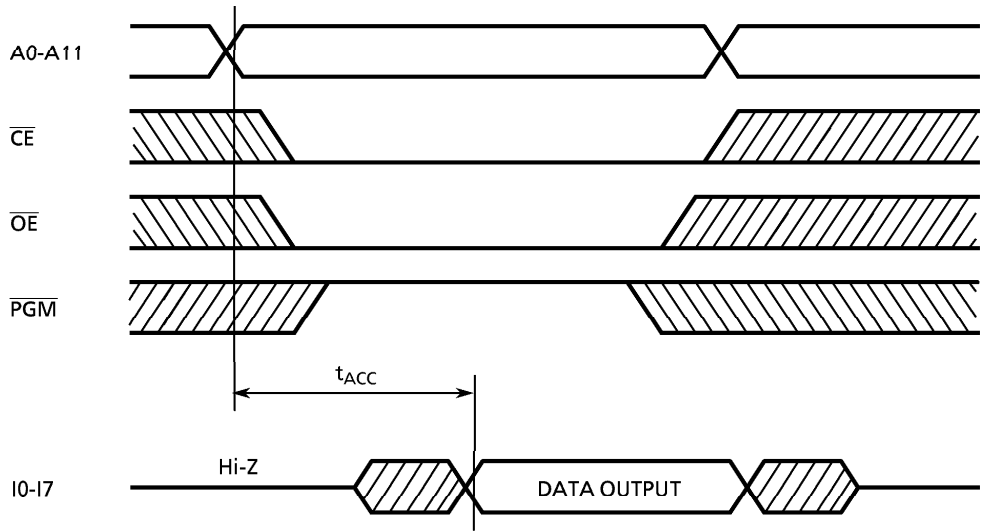
Recommended oscillating conditions of the 47P407V are equal to the 47C407A's.

## D.C./A.C. CHARACTERISTICS

(V<sub>SS</sub> = 0V)

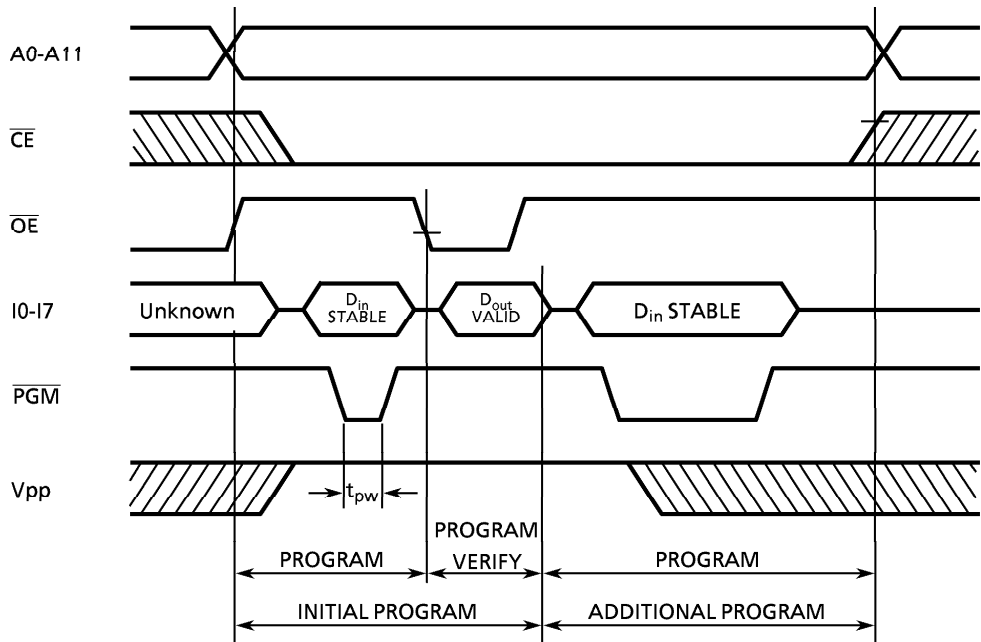
## (1) Read Operation

PARAMETER	SYMBOL	CONDITION	Min.	Typ.	Max.	UNIT
Output Level High Voltage	V <sub>IH4</sub>		V <sub>CC</sub> × 0.7	—	V <sub>CC</sub>	V
Output Level Low Voltage	V <sub>IL4</sub>		0	—	V <sub>CC</sub> × 0.3	V
Supply Voltage	V <sub>CC</sub>		4.75	—	6.0	V
Programming Voltage	V <sub>PP</sub>					
Address Access Time	t <sub>ACC</sub>	V <sub>CC</sub> = 5.0 ± 0.25V	0	—	350	ns



(2) High Speed Programming Operation

PARAMETER	SYMBOL	CONDITION	Min.	Typ.	Max.	UNIT
Input High Voltage	$V_{IH4}$		$V_{CC} \times 0.7$	–	$V_{CC}$	V
Input Low Voltage	$V_{IL4}$		0	–	$V_{CC} \times 0.3$	V
Supply Voltage	$V_{CC}$		4.75	–	6.0	V
$V_{PP}$ Power Supply Voltage	$V_{PP}$		12.0	12.5	13.0	V
Programming Pulse Width	$t_{PW}$	$V_{CC} = 6.0 \pm 0.25V$	0.95	1.0	1.05	ms



## TYPICAL CHARACTERISTICS

